NSN 5961-01-516-3775

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-516-3775 **Inclosure Material:** Plastic **Overall Length:** Between 2.790 millimeters and 3.050 millimeters **Overall Height:** Between 0.890 millimeters and 1.100 millimeters Overall Width: Between 2.100 millimeters and 2.500 millimeters **End Application:** General purpose electronic test equipment gpete; 6625-01-462-7491. **Mounting Facility Quantity:** 3 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 repetitive peak reverse voltage and 70.0 working peak reverse voltage **Current Rating Per Characteristic:** 250.00 milliamperes forward current, average **Product Name:** Fast switching diode **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: